NSN 5961-01-353-5524

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-353-5524 **Inclosure Material:** Glass or plastic **Overall Length:** Between 0.130 inches and 0.300 inches **Terminal Length:** 0.900 inches **Overall Diameter:** Between 0.115 inches and 0.180 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 480.0 breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 amperes forward current, average absolute and 100.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Clear insulation tubing; 1 st wire lead is 3.700 in. Lg, 2 nd lead is 2.300 in. Lg; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 insulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No